# NSN 5980-01-418-3876

Light Emitting Diode - Page 1 of 1



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# Inclosure Material:

Metal

# Semiconductor Material:

Gallium arsenide phosphide

# Voltage Rating In Volts Per Characteristic:

5.0 breakdown voltage, dc

# Power Rating Per Characteristic:

120.0 milliwatts small-signal input power, common-collector of standard range

## Color Tone Produced Per Source:

Green semiconductor

## Luminous Intensity:

3.0 millicandela

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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